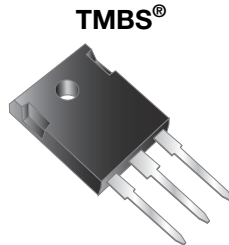
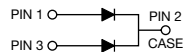


Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.54 \text{ V}$ at $I_F = 5 \text{ A}$



TO-3PW



FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition



RoHS
COMPLIANT
HALOGEN
FREE

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, dc-to-dc converters and reverse battery protection.

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 x 30 A
V_{RRM}	200 V
I_{FSM}	300 A
E_{AS} at $L = 60 \text{ mH}$	150 mJ
V_F at $I_F = 30 \text{ A}$	0.77 V
$T_J \text{ max.}$	150 °C

MECHANICAL DATA

Case: TO-3PW

Molding compound meets UL 94 V-0 flammability rating
Base P/N-M3 - halogen-free and RoHS compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	V60200PGW	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	200	V
Maximum average forward rectified current (fig. 1)		per device	60
		per diode	30
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	300	A
Non-repetitive avalanche energy at $T_J = 25 \text{ °C}$, $L = 60 \text{ mH}$ per diode	E_{AS}	150	mJ
Peak repetitive reverse current at $t_p = 2 \text{ } \mu\text{s}$, 1 kHz, $T_J = 38 \text{ °C} \pm 2 \text{ °C}$ per diode	I_{RRM}	0.5	A
Voltage rate of change (rated V_R)	dV/dt	10 000	V/ μs
Operating junction and storage temperature range	T_J, T_{STG}	- 40 to + 150	°C

V60200PGW

Vishay General Semiconductor



ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Breakdown voltage	I _R = 1.0 mA	T _A = 25 °C	V _{BR}	200 (minimum)	-	V
Instantaneous forward voltage per diode	I _F = 10 A	T _A = 25 °C	V _F ⁽¹⁾	0.69	-	V
	I _F = 15 A			0.90	-	
	I _F = 30 A			1.28	1.48	
	I _F = 10 A	T _A = 125 °C		0.54	-	
	I _F = 15 A			0.66	-	
	I _F = 30 A			0.77	0.85	
Reverse current per diode	V _R = 180 V	T _A = 25 °C	I _R ⁽²⁾	3.4	-	μA
		T _A = 125 °C		4.6	-	mA
	V _R = 200 V	T _A = 25 °C		-	210	μA
		T _A = 125 °C		7.5	27	mA

Notes

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
- (2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER		SYMBOL	V60200PGW	UNIT
Typical thermal resistance	per diode	R _{θJC}	1.5	°C/W
	per device		0.8	

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-3PW	V60200PGW-M3/4W	4.5	4W	30/tube	Tube

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

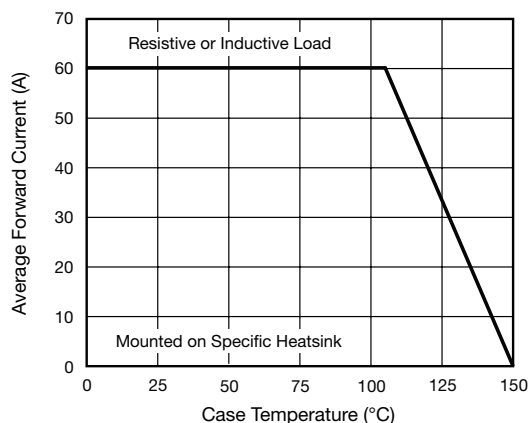


Fig. 1 - Forward Current Derating Curve

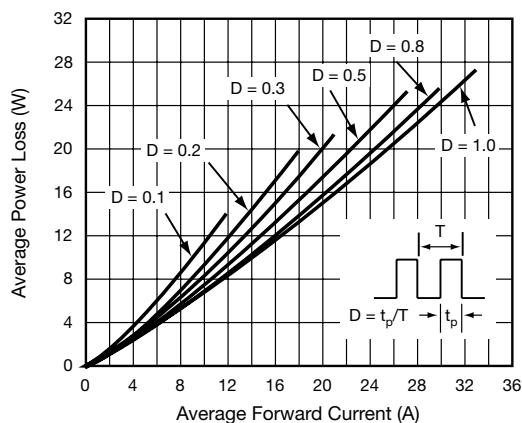


Fig. 2 - Forward Power Loss Characteristics Per Diode

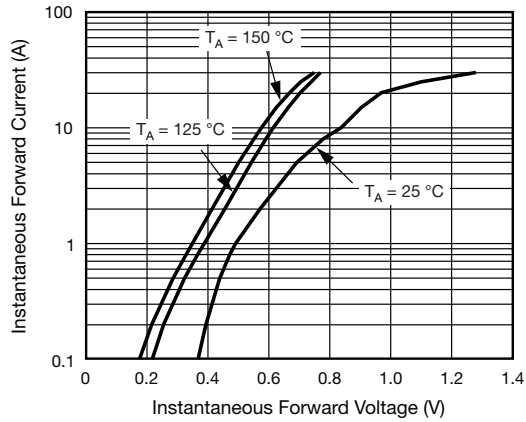


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

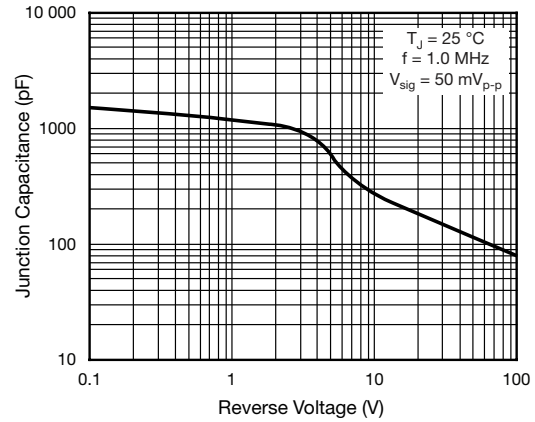


Fig. 5 - Typical Junction Capacitance Per Diode

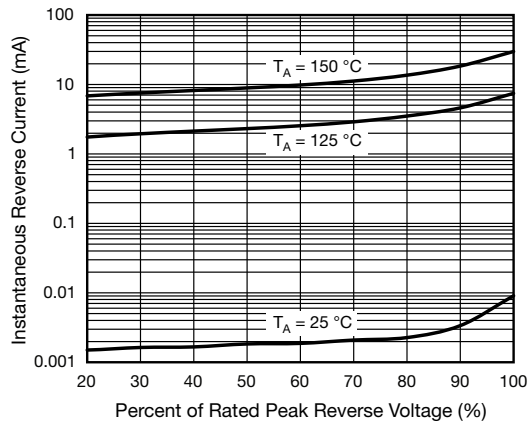


Fig. 4 - Typical Reverse Characteristics Per Diode

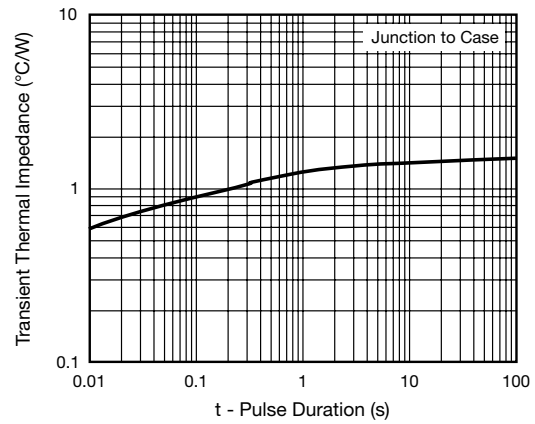
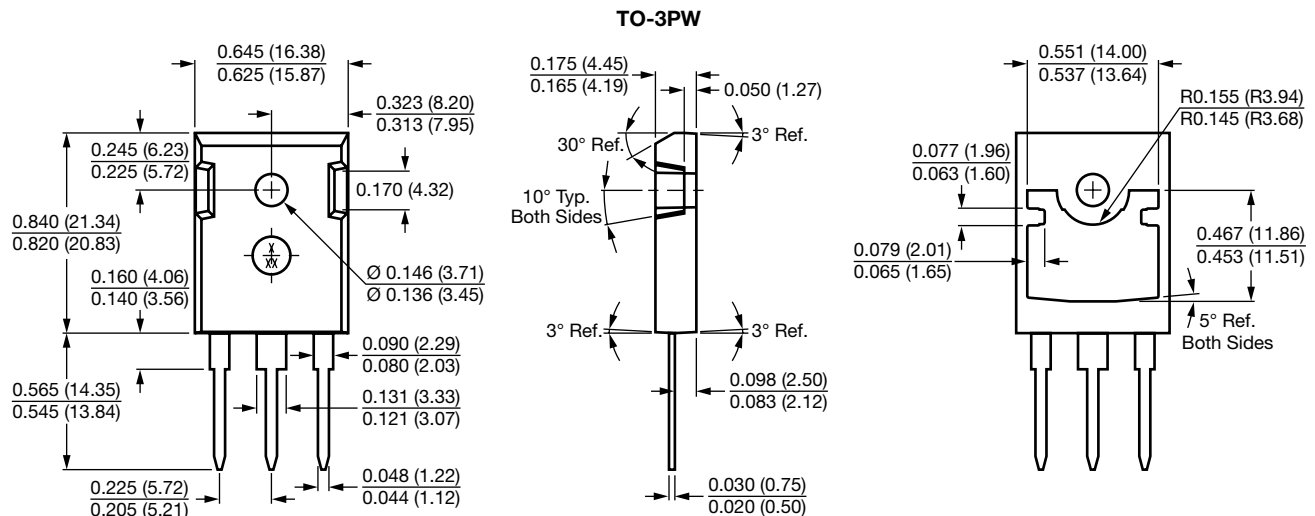


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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